VS-VSUD360CW40

Vishay Semiconductors

FRED Pt[®] Ultrafast Soft Recovery Diode Module, 360 A



PRODUCT SUMMARY				
I _{F(AV)}	360 A			
V _R	400 V			
Q _{rr} (typical)	1250 nC			
t _{rr}	40 ns			
Туре	Modules - Diode, FRED Pt®			

FEATURES

- Very low Q_{rr} and t_{rr}
- UL approved file E222165
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing

DESCRIPTION

FRED Pt[®] diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are a significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		400	V	
		T _C = 25 °C	510		
Continuous forward current per diode	I _{F(AV)}	T _C = 85 °C	305	^	
		T _C = 116 °C	180	A	
Single pulse forward current per diode	I _{FSM}		1200		
	D	T _C = 25 °C	570	W	
Maximum power dissipation P _D		T _C = 110 °C	180	vv	
Operating junction and storage temperatures	T _J , T _{Stg}		-40 to 150	°C	

ELECTRICAL SPECIFICATIONS PER LEG (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Breakdown voltage	V _{BR}	V _{BR} I _R = 100 μA		-	-	
	I _F = 180 A	-	1.09	1.27		
	V	I _F = 360 A		1.23	1.50	V
Forward voltage	V _{FM}	I _F = 180 A, T _J = 150 °C	-	0.88	0.96	
		I _F = 360 A, T _J = 150 °C	-	1.04	1.18	
Reverse leakage current	I _{RM}	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	0.26	1.28	mA
Series inductance	Ls	From top of terminal hole to mounting plane - 5 -		-	nH	







Vishay Semiconductors

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		I _F = 1.0 A, dI _F /dt = 200 A/μs, V _R = 30 V		-	40	69	
Reverse recovery time	t _{rr}	$T_J = 25 \ ^{\circ}C$	I _F = 180 A, dI _F /dt = 200 A/μs,	-	74	-	ns
		T _J = 150 °C	$V_{\rm R} = 200 \text{ V}$	-	171	-	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 20$	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		5.1	-	
Peak recovery current I _{RRM}		I_F = 180 A, dI_F/dt = 200 A/µs, V_R = 200 V		-	6.6	-	А
		$I_F = 180 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 200 \text{ V}, \text{ T}_J = 150 \ ^\circ\text{C}$		-	15.2	-	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	125	-	
Reverse recovery charge	Q _{rr}	$I_F = 180 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 200 \text{ V}$		-	243	-	nC
			I_F = 180 A, dI_F/dt = 200 A/µs, V_R = 200 V, T_J = 150 $^\circ C$		1295	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS	
Thermal resistance,	per leg		-	-	0.19		
junction to case	per module	R _{thJC}	-	-	0.095	°C/W	
Thermal resistance, case to heatsink (flag grease	ed surface)	R _{thCS}	-	0.10	-		
Waight			-	68	-	g	
Weight			-	2.4	-	oz.	
Mounting torque			30 (3.4)	-	40 (4.6)		
Mounting torque center hole Terminal torque			12 (1.4)	-	18 (2.1)	lbf ⋅ in (N ⋅ m)	
			30 (3.4)	-	40 (4.6)	(11 11)	
Vertical pull 2" lever pull			-	-	80	line in	
			-	-	35	— lbf · in	
Case style	Case style TO-244 (TO-244AB)				•		

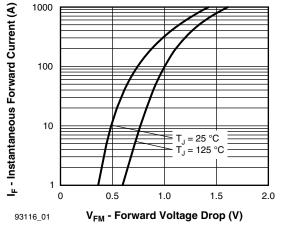
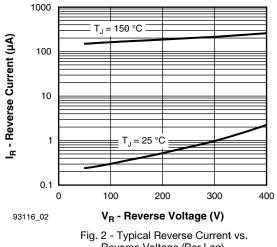


Fig. 1 - Typical Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)



Reverse Voltage (Per Leg)

Revision: 26-Mar-14

2

Document Number: 93116

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



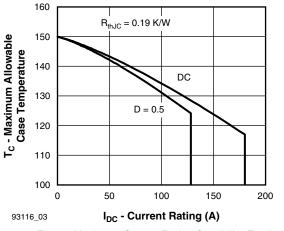
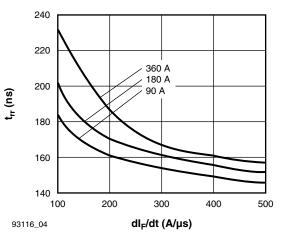
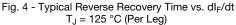


Fig. 3 - Maximum Current Rating Capability (Per Leg)

Vishay Semiconductors





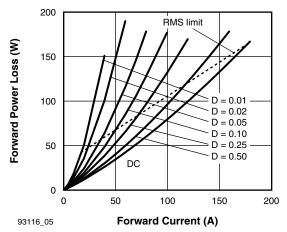


Fig. 5 - Forward Power Loss Characteristics

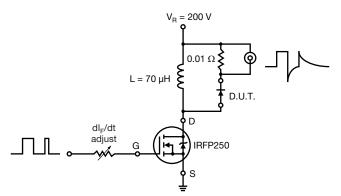
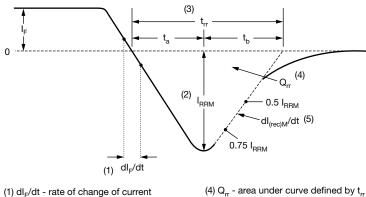


Fig. 6 - Reverse Recovery Parameter Test Circuit

Revision: 26-Mar-14 3 Document Number: 93116 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

VS-VSUD360CW40

Vishay Semiconductors



through zero crossing

- (2) I_{RRM} peak reverse recovery current (3) t_{rr} - reverse recovery time measured
- from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

 $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$

(5) dl_{(rec)M}/dt - peak rate of change of current during $t_{\rm b}$ portion of $t_{\rm rr}$

Fig. 7 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

D

www.vishay.com

evice code	vs-vs	UD	360	с	w	40	
	1	2	3	4	5	6	•
	1 -	Vish	ay Semi	conduct	ors pro	duct	
	2 -	Туре	e of devi	ce: UD =	= FRED	Pt [®]	
	3 -	Curre	ent ratin	g (360 =	= 360 A))	
	4 -	Circu	uit config	guration:			
		C = (Commo	n cathoo	le		
	5 -	Туре	e of devi	ce:			
		W =	TO-244	wire bo	ndable	not isola	ated
	6 -	Volta	age ratin	g (40 =	400 V)		

CIRCUIT CONFIGURATION				
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING		
Two diodes common cathodes	С	Lug anode 2 Base common cathode terminal anode 1		

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95021		

Revision: 26-Mar-14

4

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

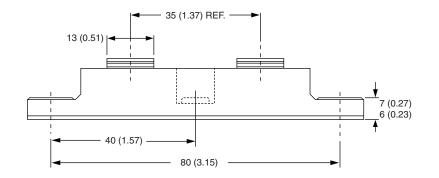


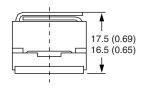


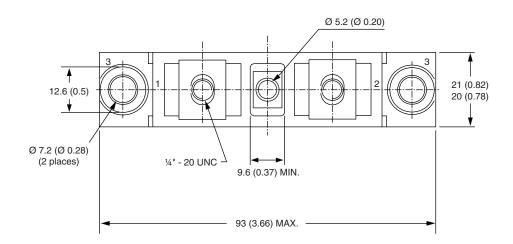
Vishay Semiconductors

TO-244

DIMENSIONS in millimeters (inches)









Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.